

Product Summary

Device	BV _{DSS}	RDS(ON) Max	I _{D MAX} Та = +25°С
Q1	20V	25mΩ @ V _{GS} = 4.5V	6.0A
N-Channel	200	35mΩ @ V _{GS} = 2.5V	5.1A
Q2	201/	75mΩ @ V _{GS} = -4.5V	-3.5A
P-Channel	-20V	140mΩ @ V _{GS} = -2.5V	-2.5A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

U-DFN2020-6 (Type B)

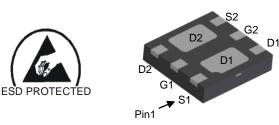
- Load Switch
- Power Management Functions
- Portable Power Adaptors

Features

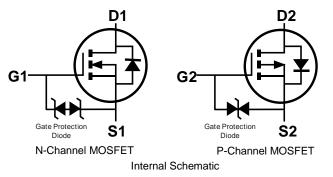
- PCB Footprint of 4mm²
- Low On-Resistance
- Low Input Capacitance
- Low Profile, 0.6mm Maximum Height
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @
- Terminals Connections: See Diagram Below
- Weight: 0.0065 grams (Approximate)



Bottom View



Ordering Information (Note 4)

Part Number	Case	Packaging
DMC2025UFDB-7	U-DFN2020-6 (Type B)	3000/Tape & Reel
DMC2025UFDB-13	U-DFN2020-6 (Type B)	10,000/Tape & Reel

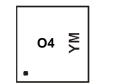
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Site 1



O4 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code I	Key
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Year	2017		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	E		Н		J	K	L	М	Ν	0	Р	R
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2



O4 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

Year	2017		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	7		0	1	2	3	4	5	6	7	8	9
Week	k 1-26				27-52				52			
Code			-20				-			J	<u> </u>	
Code		P	-Z	a-z z								
Internal Code	Sur	า	Mon		Tue	W	ed	Thu		Fri		Sat
Code	Т		U		V	V	V	Х		Y		Ζ



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic			Symbol	Q1 N-CHANNEL	Q2 P-CHANNEL	Unit
Drain-Source Voltage			Vdss	20	-20	V
Gate-Source Voltage			Vgss	±10	±8	V
Continuous Drain Current (Note 6) N-Channel: V _{GS} = 4.5V P-Channel: V _{GS} = -4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	6.0 4.8	-3.5 -2.8	А
Maximum Continuous Body Diode Forward Cur	rent (Note 6)	Is	2	-1.0	А
Pulsed Drain Current (10µs Pulse, Duty Cycle =	= 1%)		I _{DM}	20	-10	А
Avalanche Current (L = 0.1mH) (Note 7)			las	8	-13	А
Avalanche Energy (L = 0.1mH) (Note 7)			Eas	8	8.5	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	0.7	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	178	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Rəja	92	80 M/
Thermal Resistance, Junction to Case (Note 6)		Rejc	30	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics Q1 N-CHANNEL (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BVDSS	20	_	—	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	—	_	1	μA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	—		±10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	0.5		1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance	Bacion			25	mΩ	$V_{GS} = 4.5V, I_{D} = 4A$
	RDS(ON)		_	35	11152	$V_{GS} = 2.5V, I_{D} = 4A$
Diode Forward Voltage	Vsd	—	0.7	1.2	V	$V_{GS} = 0V$, $I_{S} = 5A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	—	486	—		
Output Capacitance	Coss	—	92	—	pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	77	—		
Gate Resistance	Rg	—	3.2	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	—	5.9	—		
Total Gate Charge (V _{GS} = 10V)	Qg	—	12.3	—	nC	Vps = 10V. lp = 6.5A
Gate-Source Charge	Qgs	—	0.8	—		$v_{DS} = 10v$, $i_D = 0.5A$
Gate-Drain Charge	Q _{gd}	—	2.2	—		
Turn-On Delay Time	t _{D(ON)}	—	3.4	—		
Turn-On Rise Time	tR	—	5.4	—		V _{DS} = 10V, V _{GS} = 4.5V,
Turn-Off Delay Time	tD(OFF)	—	17.6	—	ns	$R_g = 6\Omega$, $R_L = 10\Omega$, $I_D = 1A$
Turn-Off Fall Time	tF	—	9.3	—]	
Reverse Recovery Time	trr	—	7.7	_	ns	IF = 1A, di/dt = 100A/µs
Reverse Recovery Charge	Q _{RR}		1.5	_	nC	IF = 1A, di/dt = 100A/µs

 Device mounted on FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PCB, 2oz copper, with 1inch square copper plate. Notes:

7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing.



Electrical Characteristics Q2 P-CHANNEL (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BVDSS	-20	_	_	V	$V_{GS} = 0V, I_D = -250 \mu A$
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	—	_	-1.0	μA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	—	_	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						•
Gate Threshold Voltage	Vgs(th)	-0.35	_	-1.4	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Static Drain-Source On-Resistance	Deserve	_		75	mΩ	V _{GS} = -4.5V, I _D = -2.9A
	Rds(on)	—	_	140	11122	V _{GS} = -2.5V, I _D = -2.3A
Diode Forward Voltage	Vsd	—	—	-1.2	V	V _{GS} = 0V, I _S = -3.0A
DYNAMIC CHARACTERISTICS (Note 9)						•
Input Capacitance	Ciss	—	642	—	pF	
Output Capacitance	Coss	_	98	—	pF	− V _{DS} = -10V, V _{GS} = 0V, − f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	87	—	pF	
Gate Resistance	Rg	_	26.5	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = -4.5V)	0	—	8.8	_	nC	
Total Gate Charge (V _{GS} = -8V)	Qg Qg	_	15	_	nC	
Gate-Source Charge	Q _{gs}	—	0.9	_	nC	V _{DS} = -10V, I _D = -3.7A
Gate-Drain Charge	Q _{gd}	_	2.9	_	nC	
Turn-On Delay Time	td(on)	_	5.5	_	ns	
Turn-On Rise Time	tR	_	22.6		ns	V _{DD} = -10V, V _{GS} = -4.5V,
Turn-Off Delay Time	tD(OFF)	—	34.1	—	ns	$R_L = 3.3\Omega, R_g = 1\Omega$
Turn-Off Fall Time	tF	—	34.3	—	ns	
Body Diode Reverse Recovery Time	trr	—	13	—	ns	Is = -3.0A, dI/dt = 100A/µs
Body Diode Reverse Recovery Charge	Qrr	_	3.3	_	nC	Is = -3.0A, dl/dt = 100A/µs

Notes:8. Short duration pulse test used to minimize self-heating effect.9. Guaranteed by design. Not subject to product testing.



2

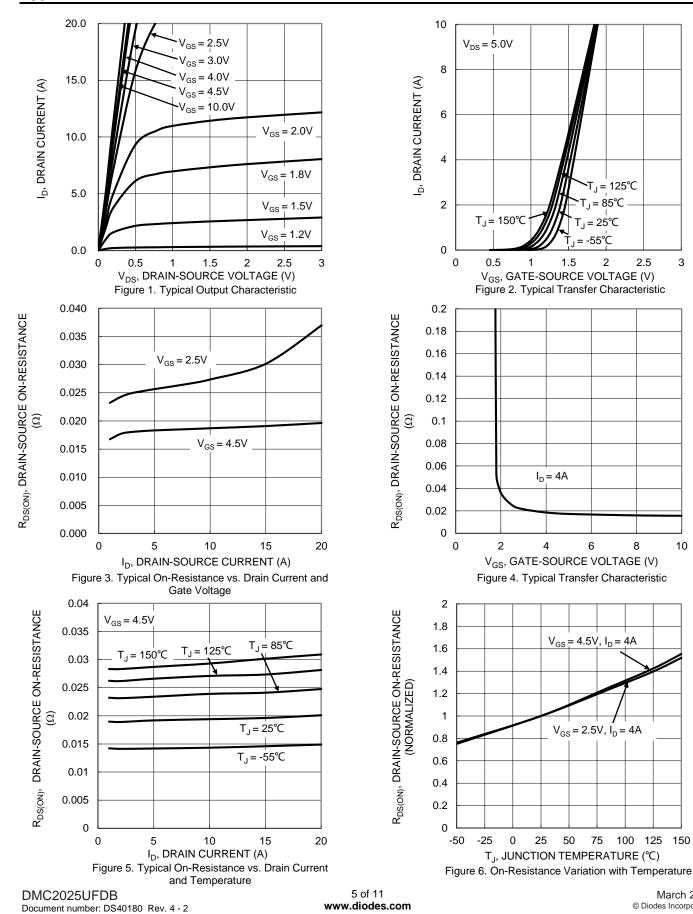
2.5

8

10

3

Typical Characteristics - N-CHANNEL



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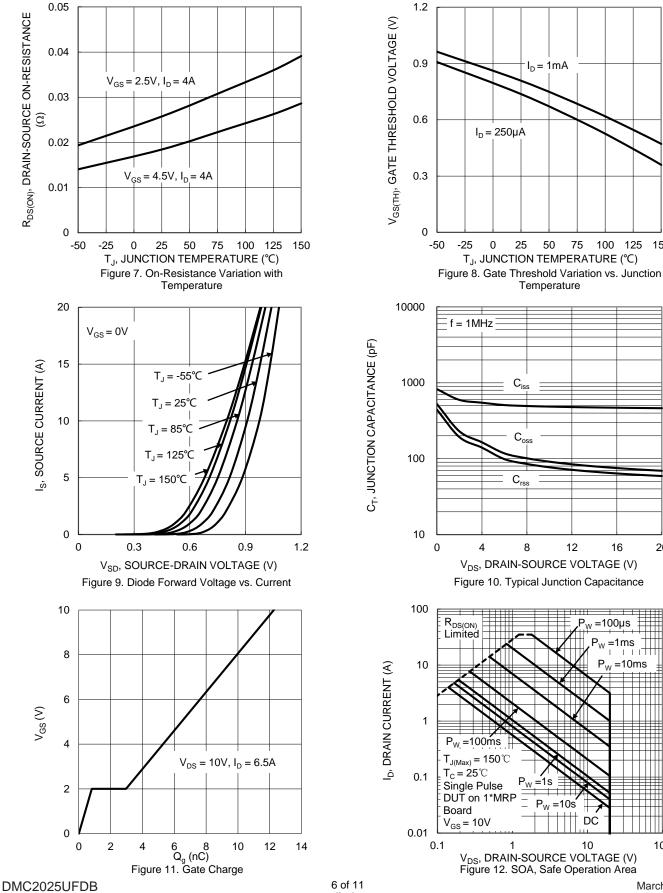
100 125 150



150

20

Typical Characteristics - N-CHANNEL (continued)



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100



T_J = 125℃

2

2.5

3

__= 85°C

= 25°C

-55℃

1.5

4

5

-2 9A _

75

50

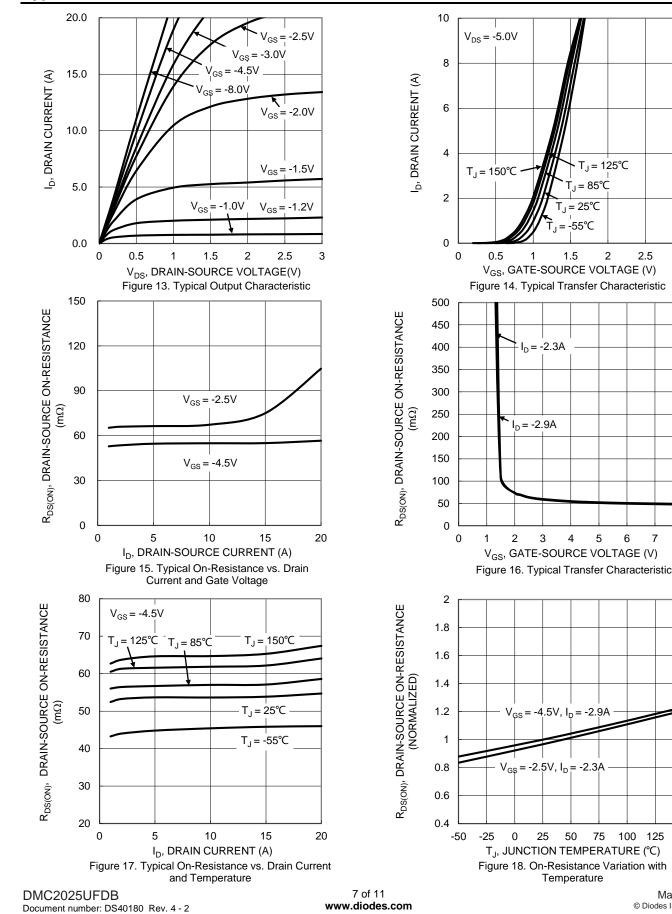
Temperature

6

7

8

Typical Characteristics - P-CHANNEL



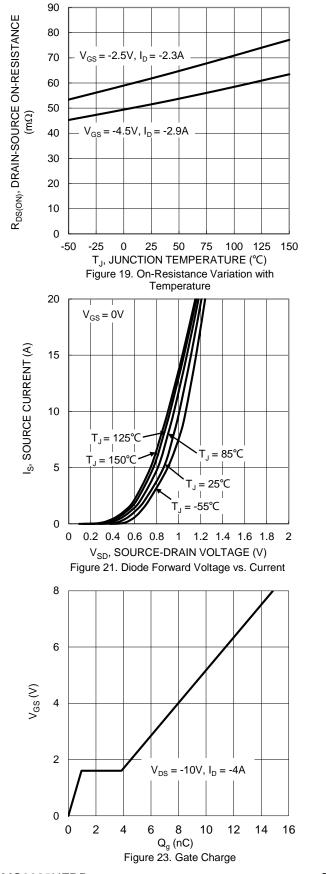
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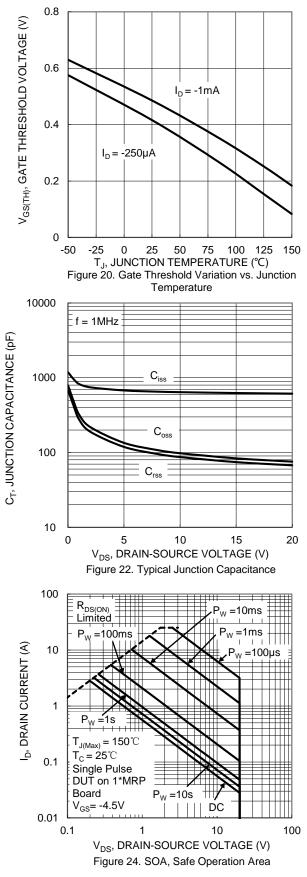
150

100 125



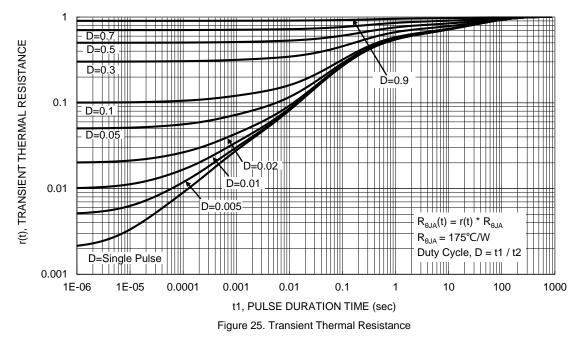
Typical Characteristics - P-CHANNEL (continued)





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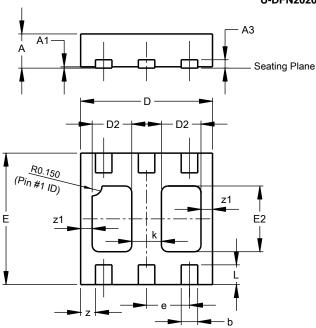






Package Outline Dimensions

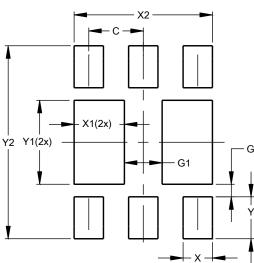
Please see http://www.diodes.com/package-outlines.html for the latest version.



l	U-DEN	2020-6						
Type B								
Dim	Min	Max	Тур					
Α	0.545	0.605	0.575					
A1	0.00	0.05	0.02					
A3		_	0.13					
b	0.20	0.30	0.25					
D	1.95	2.075	2.00					
D2	0.50	0.70	0.60					
е	_		0.65					
ш	1.95	2.075	2.00					
E2	0.90	1.10	1.00					
k		_	0.45					
L	0.25	0.35	0.30					
z		_	0.225					
z1	_		0.175					
All	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN2020-6 (Type B)

Dimensions	Value (in mm)
С	0.650
G	0.150
G1	0.450
Х	0.350
X1	0.600
X2	1.650
Y	0.500
Y1	1.000
Y2	2.300

U-DFN2020-6 (Type B)



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